Linear IC General purpose Converter cmos

D/A Converter for Digital Tuning

(12 channels. 8-bit, with OP amplifier)

MB88346B

■ DESCRIPTION

The MB88346B features 12 channels of 8-bit D/A converters with output amplifier for digital tuning. The output amplifier provides high current drive capability.

As the MB88346B inputs data in serial, it requires only three control lines and can also be cascade-connected with the MB88340 series.

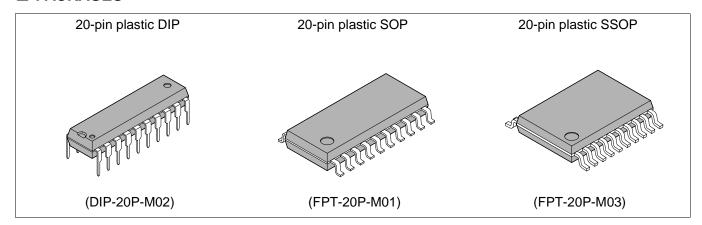
The MB88346B is suitable for electronic volumes and replacement for potentiometers for adjustment, in addition to normal D/A converter applications.

■ FEATURES

- · Low power consumption
- Small package
- Integrating 12 channels of R-2R type 8-bit D/A converter

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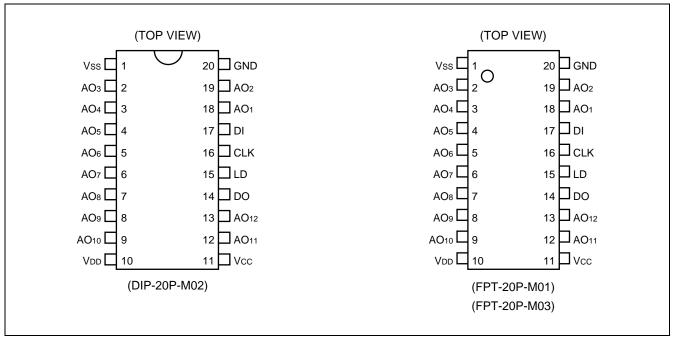
■ PACKAGES





- Built-in analog output amplifier (Max +1.0 mA sink/source current)
- Analog output range : 0 to Vcc
- The range of D/A conversion can be independently set by separated the power supply for MCU interface and OP amplifier and the power supply for D/A converter.
- Capable of being controlled directly by a 3-V MCU (input voltage: "H" = 0.5 Vcc, "L" = 0.2 Vcc)
- Serial data input, 2.5 MHz operation
- CMOS process
- Package lineup : DIP 20-pin, SOP 20-pin, SSOP 20-pin

■ PIN ASSIGNMENTS

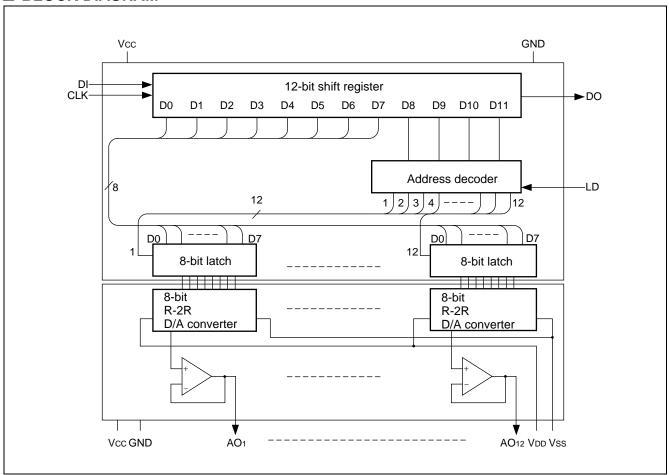


■ PIN DESCRIPTION

Pin No.	Symbol	I/O	Pin name	Function		
17	DI*	I	Data input pin	This pin inputs 12-bit serial data.		
14	DO	0	Data output pin	This pin outputs MSB bit data of 12-bit shift register.		
16	CLK*	I	Shift clock input pin	Input signal from DI pin is inputted to 12-bit shift register at rising of shift clock.		
15	LD*	I	Load signal input pin	If input "H" level to LD pin, the data of 12-bit shift register is loaded to the decoder and the register for D/A output.		
18,	AO ₁ ,					
19,	AO ₂ ,					
2,	АО3,					
3,	AO ₄ ,		D/A output pin			
4,	AO ₅ ,					
5,	AO ₆ ,	0		These pins output analog data of 8-bit D/A converter with OP amplifier.		
6,	AO ₇ ,					
7,	AO ₈ ,			,		
8,	AO ₉ ,					
9,	AO ₁₀ ,					
12,	AO ₁₁ ,					
13	AO ₁₂					
11	Vcc		Power supply pin	Power supply pin of MCU interface and OP amplifier		
20	GND		Ground pin	Ground pin of MCU interface and OP amplifier		
10	V _{DD}	_	Power supply pin	Power supply pin of D/A converter		
1	Vss		Ground pin	Ground pin of D/A converter		

^{*:} When three pins, DI, CLK, and LD pins are connected to 3-V MCU, they are fixed to "L" level at non transfer.

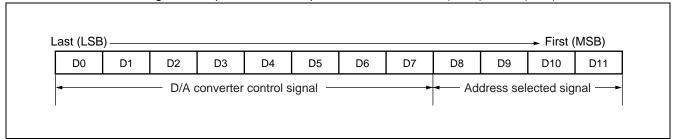
■ BLOCK DIAGRAM



■ DATA FOR CHIP CONTROL

1. Data for Shift Register

- The chip is controlled by 12 bits of data input to the shift register.
- The shift register inputs a total of 12 bits of data consisting of a four-bit address selection signal and an eight-bit D/A converter control signal.
- A data to the shift register is inputted to the DI pin in the order of D11 (MSB) to D0 (LSB) .



2. D/A Converter Control Signal

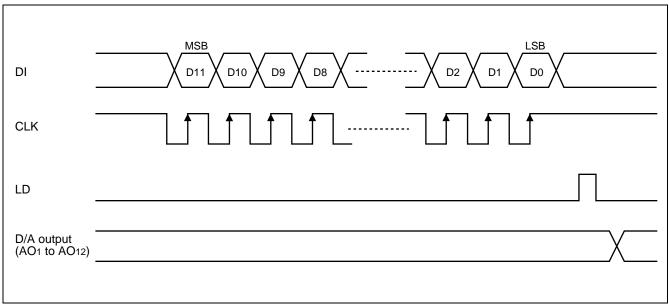
			D/A convertor quitaut voltage					
D0	D1	D2	D3	D4	D5	D6	D7	D/A converter output voltage
0	0	0	0	0	0	0	0	≅ Vss
1	0	0	0	0	0	0	0	≅ V _{REF} / 255 × 1 + V _{SS}
0	1	0	0	0	0	0	0	$\cong V_{REF} / 255 \times 2 + V_{SS}$
1	1	0	0	0	0	0	0	$\cong V_{REF} / 255 \times 3 + V_{SS}$
\$	5	5	5	5	5	5	5	\$
0	1	1	1	1	1	1	1	$\cong V_{REF} / 255 \times 254 + V_{SS}$
1	1	1	1	1	1	1	1	≅ V _{DD}

VREF = VDD - VSS

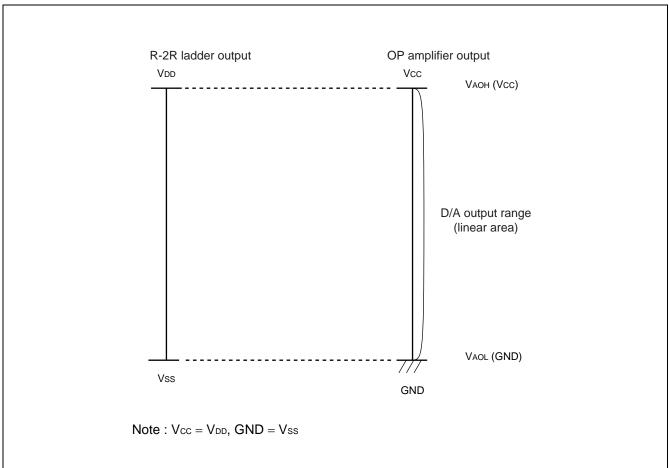
3. Address Selected Signal

	Input data signal			Address salested sequence			
D8	D9	D10	D11	Address selected sequence			
0	0	0	0	Don't Care			
0	0	0	1	AO ₁ selected			
0	0	1	0	AO ₂ selected			
0	0	1	1	AO₃ selected			
0	1	0	0	AO ₄ selected			
0	1	0	1	AO₅ selected			
0	1	1	0	AO ₆ selected			
0	1	1	1	AO ₇ selected			
1	0	0	0	AO ₈ selected			
1	0	0	1	AO ₉ selected			
1	0	1	0	AO ₁₀ selected			
1	0	1	1	AO ₁₁ selected			
1	1	0	0	AO ₁₂ selected			
1	1	0	1	Don't Care			
1	1	1	0	Don't Care			
1	1	1	1	Don't Care			

■ TIMING CHART AT DATA SETTING



■ ANALOG OUTPUT VOLTAGE RANGE



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Ra	ting	Unit	Remarks
raiailletei	Syllibol	Condition	Min	Max	Onit	Remarks
Power supply voltage	Vcc		- 0.3	+ 7.0	V	
Fower supply voltage	V_{DD}	The case that GND is referred.	- 0.3	+ 7.0	V	$V_{CC} \geq V_{DD}$
Input voltage	Vin	Ta = +25 °C	- 0.3	Vcc + 0.3	V	
Output voltage	Vоит		- 0.3	Vcc + 0.3	V	
Power consumption	PD	_	_	250	mW	
Operating temperature	Та	_	- 40	+ 85	°C	
Storage temperature	Tstg	_	- 55	+ 150	°C	

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Val	Unit	
r ai ainetei	Symbol	Min	Max	Oilit
Power supply Voltage	Vcc	4.5	5.5	V
Power supply voltage	GND	_	0	V
Analog output source current	source	_	1.0	mA
Analog output sink current	İsink	_	1.0	mA
Oscillation limited output capacitance	Соь	_	1.0	μF
Operating temperature	Та	- 40	+ 85	°C

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics

(1) Digital block

(Vdd, Vcc = + 5 V \pm 10% (Vcc \geq Vdd) , GND, Vss = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Symbol	Pin name	Conditions	Value			Unit
raiametei	Syllibol	Fililiallie	Conditions	Min	Тур	Max	Oilit
Power supply voltage	Vcc		_	4.5	5.0	5.5	V
Power supply current	Icc	Vcc	At CLK = 1 MHz operating (at no load)	_	2.5	4.5	mA
Input leakage current	lilk	CLK	Vin = 0 to Vcc	- 10		10	μΑ
"L" level input voltage	VıL	DI	_			0.2 Vcc	V
"H" level input voltage	ViH	LD	_	0.5 Vcc		_	V
"L" level output voltage	Vol	DO	IoL = 2.5 mA			0.4	V
"H" level output voltage	Vон	50	Іон = - 400 μА	Vcc - 0.4	_		V

Note: Io∟ and Ioн are output load current.

(2) Analog block

(VDD, VCC = +5 V \pm 10% (VCC \geq VDD), GND, Vss = 0 V, Ta = -40 °C to +85 °C)

Doromotor	Cumbal	Din nama	Conditions		Value		Unit
Parameter	Symbol	Pin name	Conditions	Min	Тур	Max	Unit
Consumption current	IDD	V _{DD}	No load		0.2	0.5	mA
Analog power	V _{DD}	V _{DD}	V _{DD} - V _{SS} ≥ 2.0 V	2.0		Vcc	V
supply voltage	Vss	Vss	V DD - VSS ≥ 2.0 V	GND		Vcc - 2.0	V
Resolution	Res		Monotonic increase	_	8	_	bit
Non linearity error	LE	AO ₁ to	No load $V_{DD} \le V_{CC} - 0.1 \text{ V}$ $V_{SS} \ge 0.1 \text{ V}$	- 1.5	0	1.5	LSB
Differential linearity error	DLE	71012	AO ₁₂ No load $V_{DD} \le V_{CC} - 0.1 \text{ V}$ $V_{SS} \ge 0.1 \text{ V}$			1.0	LSB
Output minimum voltage 1	V _{AOL1}		No load, Vss = 0 V When digital setting is #00.	Vss	_	Vss + 0.1	V
Output minimum voltage 2	V _{AOL2}		$I_{\text{source}} = 500 \; \mu\text{A}$ When digital setting is #00.	Vss - 2.0	Vss	Vss + 0.2	V
Output minimum voltage 3	V _{AOL3}	AO 1	$I_{\text{sink}} = 500 \; \mu A \\ \text{When digital setting is \#00.}$	Vss		Vss + 0.2	V
Output minimum voltage 4	V _{AOL4}	to AO 12	$\begin{split} V_{\text{DD}} &= V_{\text{CC}} = 5.0 \text{ V} \\ V_{\text{SS}} &= GND = 0.0 \text{ V} \\ I_{\text{source}} &= 1.0 \text{ mA} \\ When \text{ digital setting is $\#00$.} \end{split}$	Vss - 0.3	Vss	V ss + 0.3	V
Output minimum voltage 5	V _{AOL5}		$\begin{split} V_{DD} &= V_{CC} = 5.0 \text{ V} \\ V_{SS} &= GND = 0.0 \text{ V} \\ I_{sink} &= 1.0 \text{ mA} \\ When digital setting is \#00. \end{split}$	Vss	_	V ss + 0.3	V

(Continued)

(V_{DD}, V_{CC} = + 5 V \pm 10% (V_{CC} \geq V_{DD}), GND, V_{SS} = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Symbol	Pin name	Conditions		Value		Unit
rarameter	Syllibol	Filitiallie	Conditions	Min	Тур	Max	Offic
Output maximum voltage 1	V _{AOH1}		No load, $V_{DD} = V_{CC}$ When digital setting is #FF.	V _{DD} - 0.1	_	V dd	V
Output maximum voltage 2	V _{AOH2}		$\begin{array}{l} I_{\text{source}} = 500 \; \mu A \\ When \; \text{digital setting is \#FF.} \end{array}$	V _{DD} - 0.2	_	V DD	V
Output maximum voltage 3	Vаонз	AO 1	$I_{\text{sink}} = 500 \; \mu A \\ \text{When digital setting is \#FF.}$	V _{DD} - 0.2	V dd	V DD + 0.2	V
Output maximum voltage 4	Vаон4	to AO 12	$\begin{split} &V_{DD} = V_{CC} = 5.0 \text{ V} \\ &V_{SS} = GND = 0.0 \text{ V} \\ &I_{source} = 1.0 \text{ mA} \\ &When \text{ digital setting is \#FF.} \end{split}$	V _{DD} - 0.3	_	V _{DD}	V
Output maximum voltage 5	V _{AOH5}		$\begin{split} V_{\text{DD}} &= V_{\text{CC}} = 5.0 \text{ V} \\ V_{\text{SS}} &= GND = 0.0 \text{ V} \\ I_{\text{sink}} &= 1.0 \text{ mA} \\ \text{When digital setting is \#FF.} \end{split}$	V _{DD} - 0.3	V dd	V DD + 0.3	V

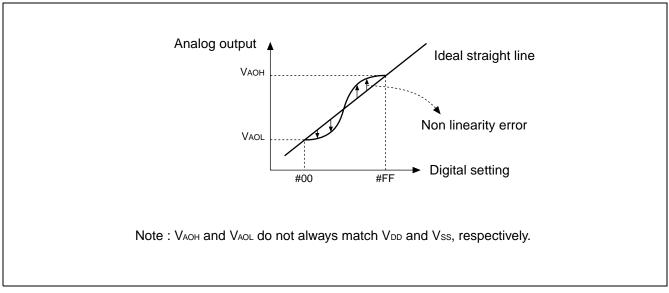
Non linearity error

: The error of the I/O curve from the ideal straight line between output voltages at "00"

and "FF".

Differential linearity error: The error from the ideal increment given when the digital value is incremented by one

bit.

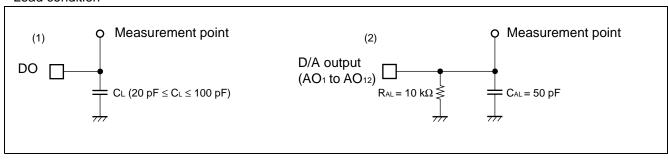


2. AC Characteristics

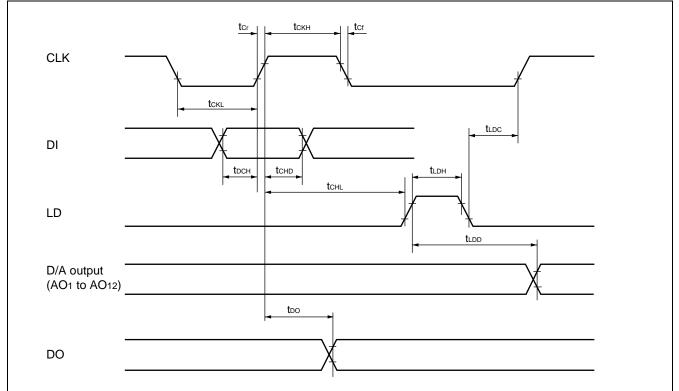
(Vdd, Vcc = + 5 V \pm 10% (Vcc \geq Vdd) , GND, Vss = 0 V, Ta = - 40 °C to + 85 °C)

Parameter	Symbol	Conditions	Va	lue	Unit
Parameter	Symbol	Conditions	Min	Max	Unit
"L" level clock pulse width	t ckl	_	200	_	
"H" level clock pulse width	tскн	_	200	_	
Clock rising time Clock falling time	tor tor	_		200	
Data setup time	t DCH	_	30	_	
Data hold time	t chd	_	60	_	ns
Load setup time	t chL	_	200	_	
Load hold time	tLDC	_	100	_	
"H" level load pulse width	t LDH	_	100	_	
Data output delay time	t _{DO}	Refer to "Load condition (1)".	70	350	
D/A output settling time	t LDD	Refer to "Load condition (2)".	_	20	μS

• Load condition

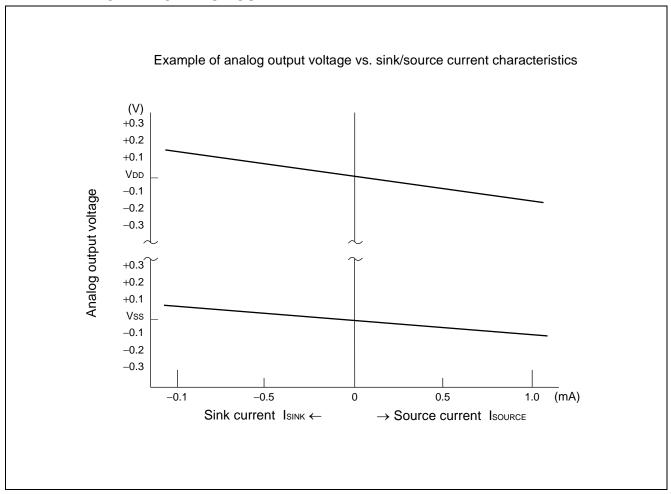


• Input/output timing



Note : The D/A output evaluation level is 90% and 10% of Vcc. The other evaluation level is 80% and 20% of Vcc.

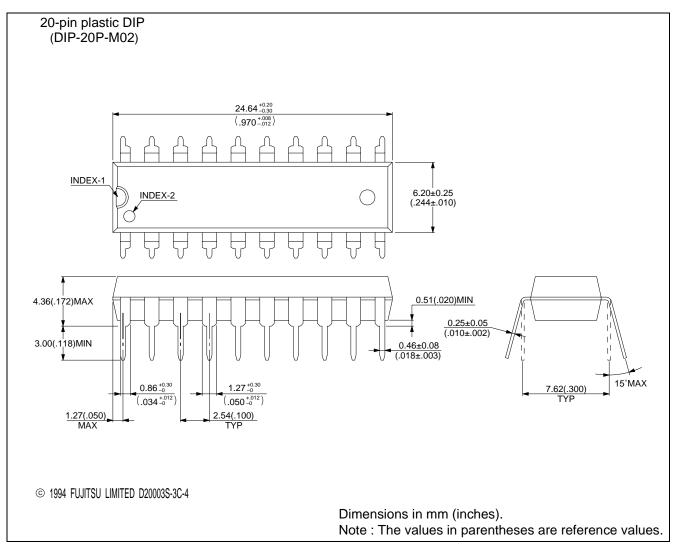
■ EXAMPLE CHARACTERISTICS

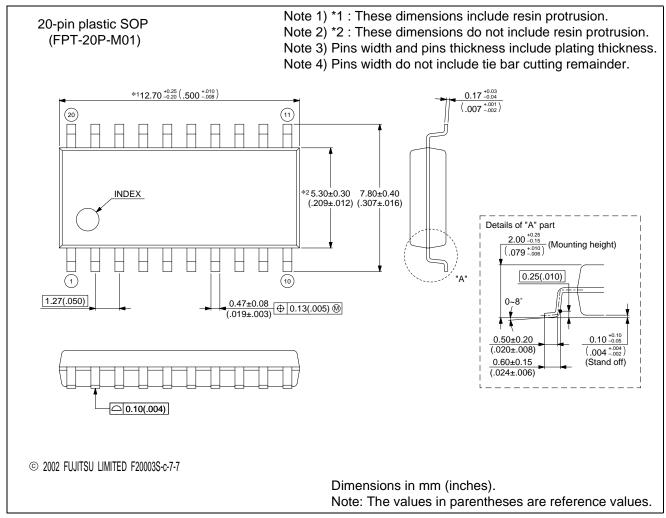


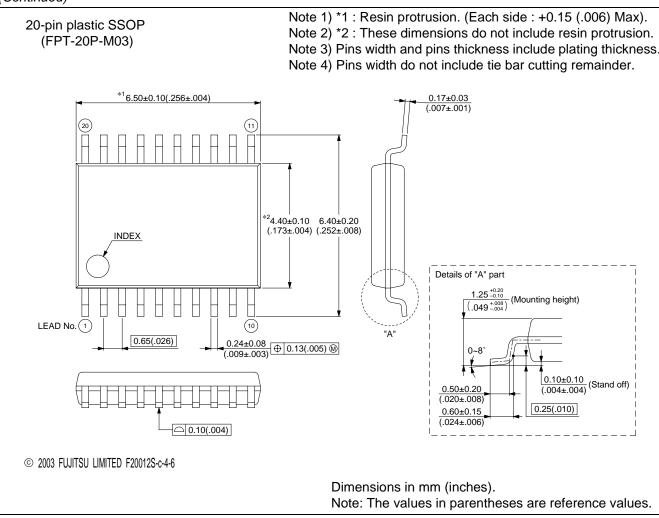
■ ORDERING INFORMATION

Part No.	Package	Remarks
MB88346BP	20-pin plastic DIP (DIP-20P-M02)	
MB88346BPF	20-pin plastic SOP (FPT-20P-M01)	
MB88346BPFV	20-pin plastic SSOP (FPT-20P-M03)	

■ PACKAGE DIMENSIONS







MEMO		

MEMO		

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